

PROCEEDINGS OF SPIE

Semiconductor Lasers and Laser Dynamics V

Krassimir Panajotov

Marc Sciamanna

Angel Valle

Rainer Michalzik

Editors

16–19 April 2012

Brussels, Belgium

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SPIE

Volume 8432

Proceedings of SPIE, 0277-786X, v. 8432

SPIE is an international society advancing an interdisciplinary approach to the science and application of light.

The papers included in this volume were part of the technical conference cited on the cover and title page. Papers were selected and subject to review by the editors and conference program committee. Some conference presentations may not be available for publication. The papers published in these proceedings reflect the work and thoughts of the authors and are published herein as submitted. The publisher is not responsible for the validity of the information or for any outcomes resulting from reliance thereon.

Please use the following format to cite material from this book:

Author(s), "Title of Paper," in *Semiconductor Lasers and Laser Dynamics V*, edited by Krassimir Panajotov, Marc Sciamanna, Angel Valle, Rainer Michalzik, Proceedings of SPIE Vol. 8432 (SPIE, Bellingham, WA, 2012) Article CID Number.

ISSN 0277-786X
ISBN 9780819491244

Published by

SPIE
P.O. Box 10, Bellingham, Washington 98227-0010 USA
Telephone +1 360 676 3290 (Pacific Time) · Fax +1 360 647 1445
SPIE.org

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Printed in the United States of America.

Publication of record for individual papers is online in the SPIE Digital Library.



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